

1. Description

This P-Channel 2.5V specified MOSFET uses Fairchild's advanced low voltage PowerTrench process. It has been optimized for battery power management applications.

2. Features

- $V_{(BR)DSS} = -20V$
- $I_D = -2.8A$
- $R_{DS(ON)} < 112m\Omega (V_{GS} = -4.5V)$
- $R_{DS(ON)} < 142m\Omega (V_{GS} = -2.5V)$

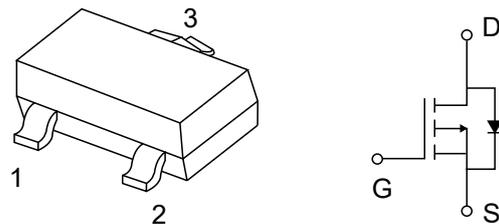
3. Application

- Load Switch for Portable Devices
- DC/DC Converter

4. Pinning information

Pin	Symbol	Description
1	G	GATE
2	S	SOURCE
3	D	DRAIN

SOT-23



5. Maximum ratings ($T_A = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 8	
Continuous Drain Current	I_D	-2.8	A
Pulsed Drain Current	I_{DM}	-10	
Continuous Source-Drain Current	I_S	-0.72	
Maximum Power Dissipation	P_D	0.4	W
Thermal Resistance from Junction to Ambient ($t \leq 5s$)	$R_{\theta JA}$	312.5	$^\circ C/W$
Junction Temperature	T_J	150	$^\circ C$
Storage Temperature	T_{STG}	-55 to 150	$^\circ C$



6. $T_A=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Conditions	Min	Typ	Max	Units	
Static							
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20			V	
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.4		-1	V	
Gate-source leakage	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$			± 100	nA	
Zero gate voltage drain current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V$			-1	μA	
Drain-source on-state resistance ^a	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-2.8A$		0.09	0.112	Ω	
		$V_{GS}=-2.5V, I_D=-2A$		0.11	0.142	Ω	
Forward transconductance ^a	g_{FS}	$V_{DS}=-5V, I_D=-2.8A$		6.5		S	
Dynamic ^b							
Input Capacitance	C_{iss}	$V_{DS}=-10V, V_{GS}=0V, f=1MHz$		405		pF	
Output Capacitance	C_{oss}			75			
Reverse Transfer Capacitance	C_{rss}			55			
Total gate charge	Q_g	$V_{DS}=-10V, V_{GS}=-2.5V, I_D=-3A$		5.5	10	nC	
				3.3	6		
Gate-source charge	Q_{gs}	$V_{DS}=-10V, V_{GS}=-2.5V, I_D=-3A$		0.7			
Gate-drain charge	Q_{gd}			1.3			
Gate resistance	R_g	$f=1MHz$		6		Ω	
Turn-on delay time	$t_{D(on)}$	$V_{DD}=-10V, R_L=10\Omega, I_D\approx -1A$		11	20	ns	
Rise time	t_r			35	60	ns	
Turn-off delay time	$t_{D(off)}$		$V_{GEN}=-4.5V, R_G=1\Omega$		30	50	ns
Fall time	t_f				10	20	ns
Drain-source body diode characteristics							
Continuous Source-Drain Diode Current	I_S	$T_C=25^\circ C$			-1.3	A	
Pulsed Diode forward Current	I_{SM}				-10	A	
Body diode voltage	V_{SD}	$I_S=-0.7A$		-0.8	-1.2	V	

Notes :

a. Pulse Test : Pulse Width < 300 μs , Duty Cycle $\leq 2\%$.

b. Guaranteed by design, not subject to production testing.

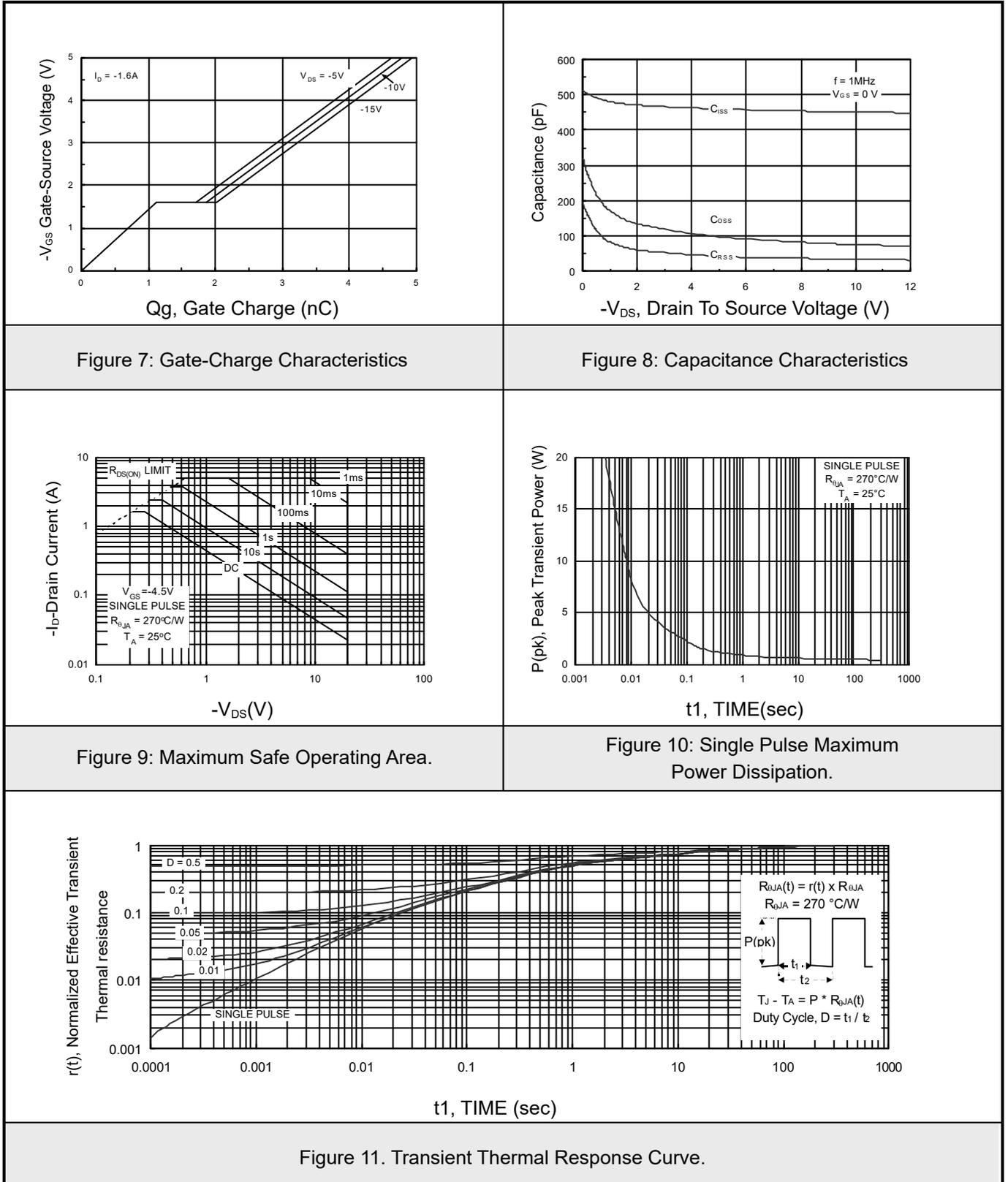


7.1 Typical Characteristics

<p>Figure 1: On-Region Characteristics.</p>	<p>Figure 2: On-Resistance Variation with Drain Current and Gate Voltage.</p>
<p>Figure 3: On-Resistance Variation with Temperature.</p>	<p>Figure 4: On-Resistance Variation with Gate-to-Source Voltage.</p>
<p>Figure 5: Transfer Characteristics.</p>	<p>Figure 6: . Body Diode Forward Voltage Variation with Source Current and Temperature.</p>

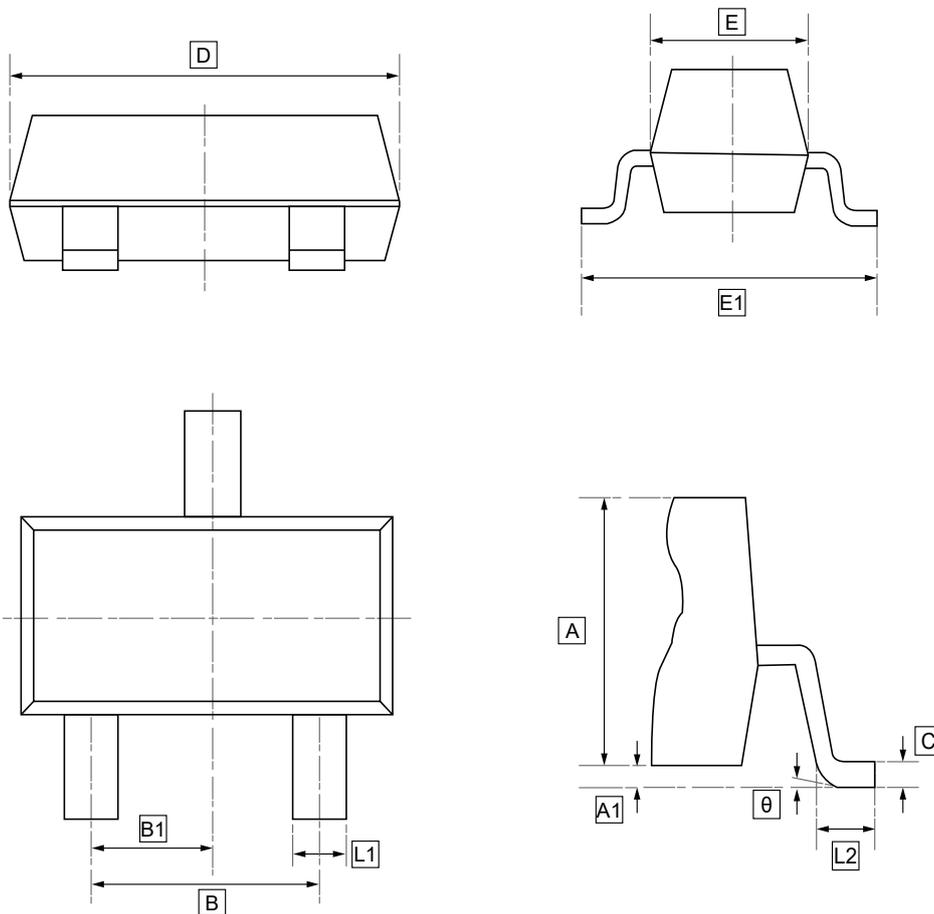


7.2 Typical Characteristics





8.SOT-23 Package Outline Dimensions

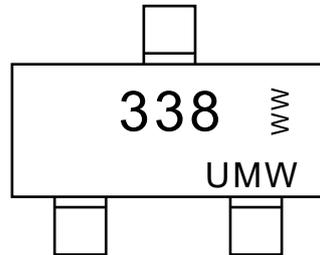


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	L1	L2	C	D	E	E1	B	B1	θ
Min	1.050	0.000	0.300	0.350	0.100	2.820	1.500	2.700	1.800	0.950	0°
Max	1.150	0.100	0.500	0.550	0.200	3.020	1.700	2.900	2.000	TYP	8°



9. Ordering information



WW: Batch Code

Order Code	Package	Base QTY	Delivery Mode
UMW FDN338P	SOT-23	3000	Tape and reel



10.Disclaimer

UMW reserves the right to make changes to all products, specifications. Customers should obtain the latest version of product documentation and verify the completeness and currency of the information before placing an order.

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